

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VCX16823FT

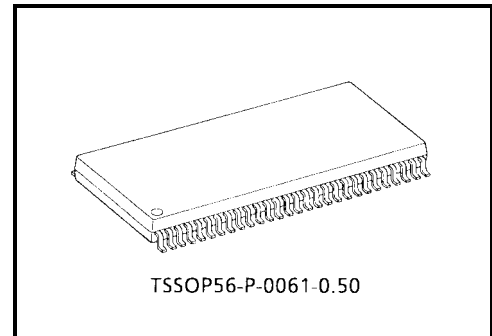
Low-Voltage 18-Bit D-Type Flip-Flop with 3.6-V Tolerant Inputs and Outputs

The TC74VCX16823FT is a high-performance CMOS 18-bit D-type flip-flop. Designed for use in 1.8-V, 2.5-V or 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

It is also designed with overvoltage tolerant inputs and outputs up to 3.6 V.

The TC74VCX16823FT can be used as two 9-bit flip-flops or one 18-bit flip-flop. With the clock-enable ($\overline{\text{CKEN}}$) input low, the D-type flip-flops enter data on the low-to-high transitions of the clock. Taking $\overline{\text{CKEN}}$ high disables the clock buffer, thus latching the outputs. Taking the clear ($\overline{\text{CLR}}$) input low causes the $\overline{\text{Q}}$ outputs to go low independently of the clock. When the $\overline{\text{OE}}$ input is high, the outputs are in a high-impedance state. This device is designed to be used with 3-state memory address drivers, etc.

All inputs are equipped with protection circuits against static discharge.

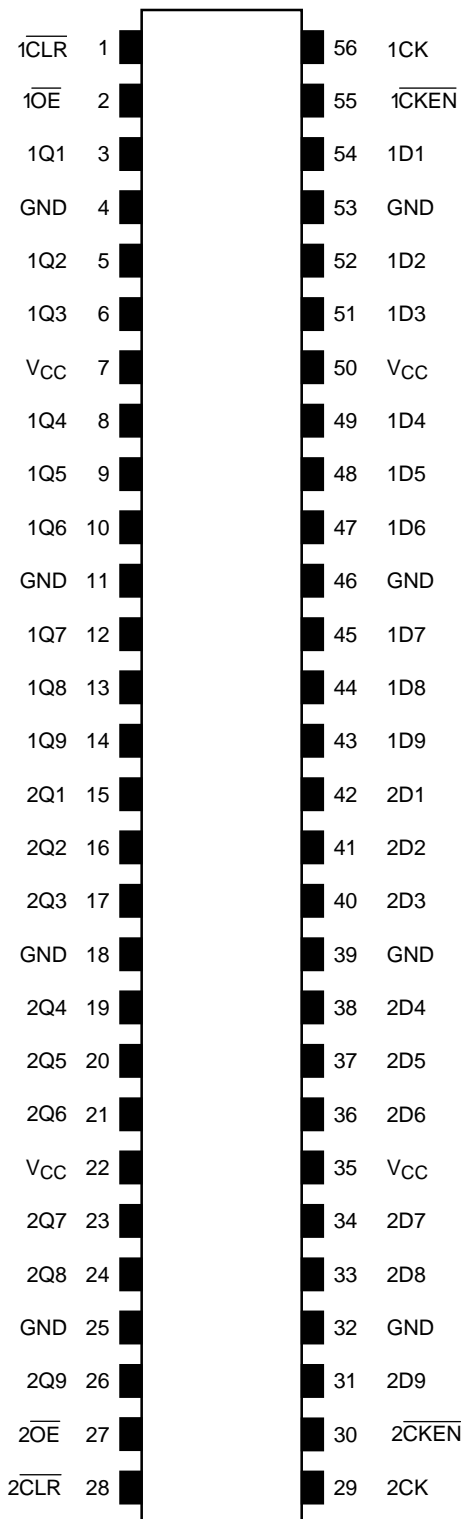


Weight: 0.25 g (typ.)

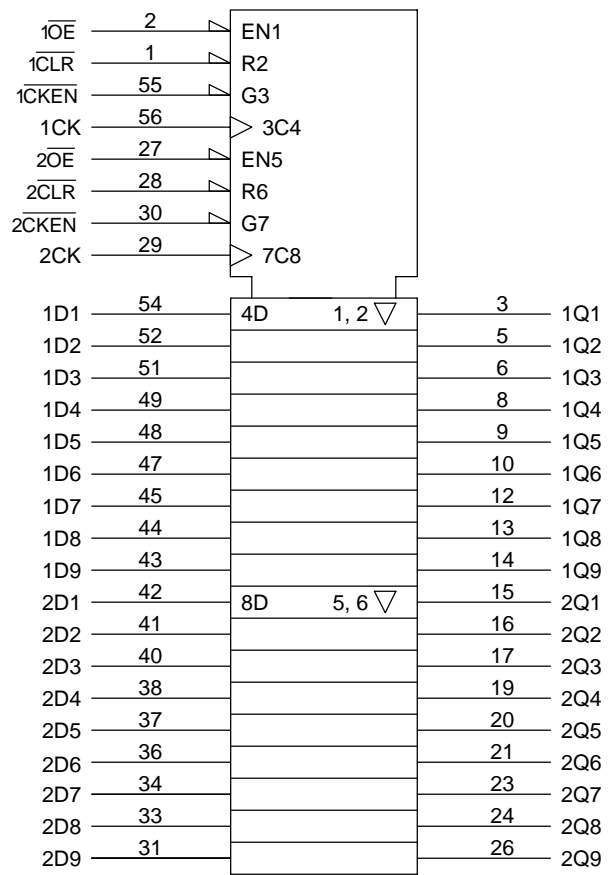
Features

- Low-voltage operation: $V_{CC} = 1.8$ to 3.6 V
- High-speed operation: $t_{pd} = 3.5$ ns (max) ($V_{CC} = 3.0$ to 3.6 V)
: $t_{pd} = 4.4$ ns (max) ($V_{CC} = 2.3$ to 2.7 V)
: $t_{pd} = 8.8$ ns (max) ($V_{CC} = 1.8$ V)
- Output current: $I_{OH}/I_{OL} = \pm 24$ mA (min) ($V_{CC} = 3.0$ V)
: $I_{OH}/I_{OL} = \pm 18$ mA (min) ($V_{CC} = 2.3$ V)
: $I_{OH}/I_{OL} = \pm 6$ mA (min) ($V_{CC} = 1.8$ V)
- Latch-up performance: ± 300 mA
- ESD performance: Machine model $> \pm 200$ V
: Human body model $> \pm 2000$ V
- Package: TSSOP (thin shrink small outline package)
- 3.6-V tolerant function and power-down protection provided on all inputs and outputs

Pin Assignment (top view)



IEC Logic Symbol



Truth Table (each 9-bit flip flop)

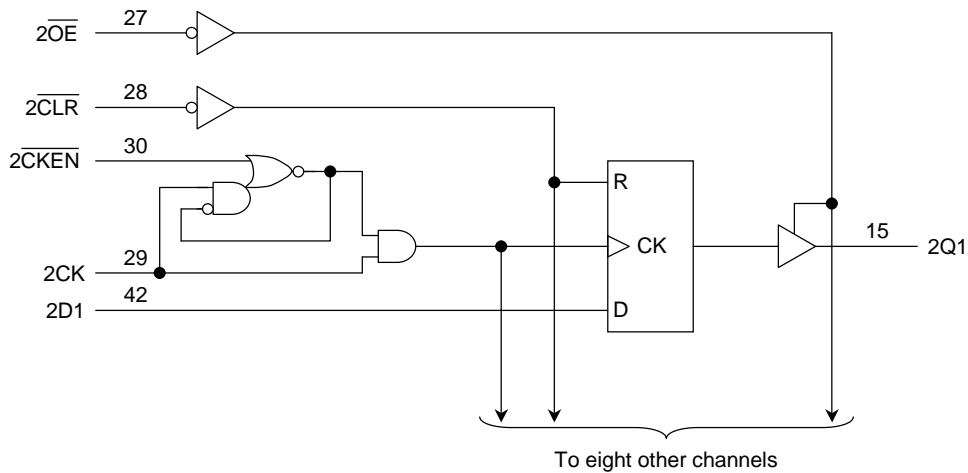
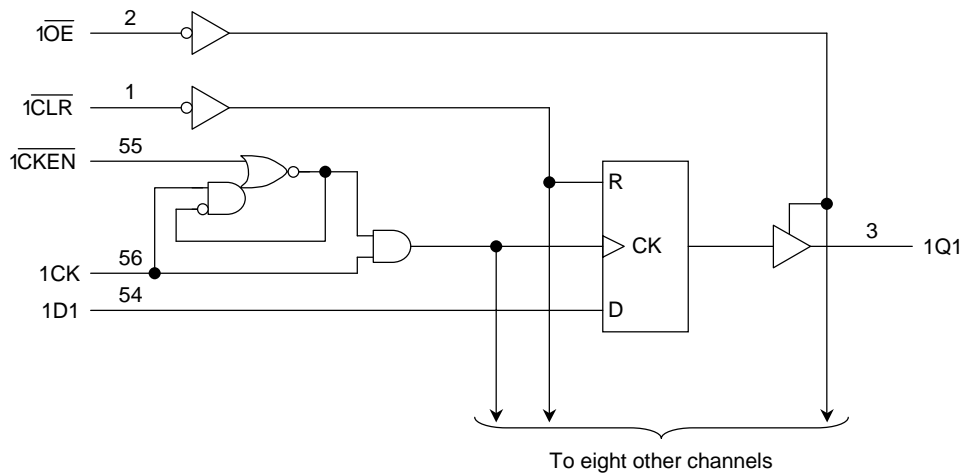
| Inputs | | | | | Outputs Q |
|-----------------|------------------|-------------------|------------|---|--------------|
| \overline{OE} | \overline{CLR} | \overline{CKEN} | CK | D | |
| L | L | X | X | X | L |
| L | H | L | \uparrow | H | H |
| L | H | L | \uparrow | L | L |
| L | H | L | L | X | Q0 |
| L | H | H | X | X | Q0 |
| H | X | X | X | X | Z |

X: Don't care

Z: High impedance

Qn: No change

System Diagram



Maximum Ratings

| Characteristics | Symbol | Rating | Unit |
|--|------------------|------------------------------------|------|
| Power supply voltage | V_{CC} | -0.5 to 4.6 | V |
| DC input voltage | V_{IN} | -0.5 to 4.6 | V |
| DC output voltage | V_{OUT} | -0.5 to 4.6 (Note 1) | V |
| | | -0.5 to $V_{CC} + 0.5$ (Note 2) | |
| Input diode current | I_{IK} | -50 | mA |
| Output diode current | I_{OK} | ± 50 (Note 3) | mA |
| DC output current | I_{OUT} | ± 50 | mA |
| Power dissipation | P_D | 400 | mW |
| DC V_{CC} /ground current per supply pin | I_{CC}/I_{GND} | ± 100 | mA |
| Storage temperature | T_{stg} | -65 to 150 | °C |

Note 1: OFF state

Note 2: High or low state. I_{OUT} absolute maximum rating must be observed.

Note 3: $V_{OUT} < GND$, $V_{OUT} > V_{CC}$

Recommended Operating Range

| Characteristics | Symbol | Rating | Unit |
|--------------------------|-----------------|------------------------|------|
| Power supply voltage | V_{CC} | 1.8 to 3.6 | V |
| | | 1.2 to 3.6 (Note 4) | |
| Input voltage | V_{IN} | -0.3 to 3.6 | V |
| Output voltage | V_{OUT} | 0 to 3.6 (Note 5) | V |
| | | 0 to V_{CC} (Note 6) | |
| Output current | I_{OH}/I_{OL} | ± 24 (Note 7) | mA |
| | | ± 18 (Note 8) | |
| | | ± 6 (Note 9) | |
| Operating temperature | T_{opr} | -40 to 85 | °C |
| Input rise and fall time | dt/dv | 0 to 10 (Note 10) | ns/V |

Note 4: Data retention only

Note 5: OFF state

Note 6: High or low state

Note 7: $V_{CC} = 3.0$ to 3.6 V

Note 8: $V_{CC} = 2.3$ to 2.7 V

Note 9: $V_{CC} = 1.8$ V

Note 10: $V_{IN} = 0.8$ to 2.0 V, $V_{CC} = 3.0$ V

Electrical Characteristics

DC Characteristics (Ta = -40 to 85°C, 2.7 V < VCC ≤ 3.6 V)

| Characteristics | | Symbol | Test Condition | | VCC (V) | Min | Max | Unit |
|---------------------------------------|---------|------------------|---|---------------------------|------------|-----------------------|-------|------|
| | | | | | | | | |
| Input voltage | H-level | V _{IH} | — | | 2.7 to 3.6 | 2.0 | — | V |
| | L-level | V _{IL} | — | | 2.7 to 3.6 | — | 0.8 | |
| Output voltage | H-level | V _{OH} | V _{IN} = V _{IH} or V _{IL} | I _{OH} = -100 μA | 2.7 to 3.6 | V _{CC} - 0.2 | — | V |
| | | | | I _{OH} = -12 mA | 2.7 | 2.2 | — | |
| | | | | I _{OH} = -18 mA | 3.0 | 2.4 | — | |
| | | | | I _{OH} = -24 mA | 3.0 | 2.2 | — | |
| | L-level | V _{OL} | V _{IN} = V _{IH} or V _{IL} | I _{OL} = 100 μA | 2.7 to 3.6 | — | 0.2 | |
| | | | | I _{OL} = 12 mA | 2.7 | — | 0.4 | |
| | | | | I _{OL} = 18 mA | 3.0 | — | 0.4 | |
| | | | | I _{OL} = 24 mA | 3.0 | — | 0.55 | |
| Input leakage current | | I _{IN} | V _{IN} = 0 to 3.6 V | | 2.7 to 3.6 | — | ±5.0 | μA |
| 3-state output OFF state current | | I _{OZ} | V _{IN} = V _{IH} or V _{IL} V _{OUT} = 0 to 3.6 V | | 2.7 to 3.6 | — | ±10.0 | μA |
| Power-off leakage current | | I _{OFF} | V _{IN} , V _{OUT} = 0 to 3.6 V | | 0 | — | 10.0 | μA |
| Quiescent supply current | | I _{CC} | V _{IN} = V _{CC} or GND | | 2.7 to 3.6 | — | 20.0 | μA |
| | | | V _{CC} ≤ (V _{IN} , V _{OUT}) ≤ 3.6 V | | 2.7 to 3.6 | — | ±20.0 | |
| Increase in I _{CC} per input | | ΔI _{CC} | V _{IH} = V _{CC} - 0.6 V | | 2.7 to 3.6 | — | 750 | |

DC Characteristics (Ta = -40 to 85°C, 2.3 V ≤ VCC ≤ 2.7 V)

| Characteristics | | Symbol | Test Condition | | VCC (V) | Min | Max | Unit |
|----------------------------------|---------|------------------|---|---------------------------|------------|-----------------------|-------|------|
| | | | | | | | | |
| Input voltage | H-level | V _{IH} | — | | 2.3 to 2.7 | 1.6 | — | V |
| | L-level | V _{IL} | — | | 2.3 to 2.7 | — | 0.7 | |
| Output voltage | H-level | V _{OH} | V _{IN} = V _{IH} or V _{IL} | I _{OH} = -100 μA | 2.3 to 2.7 | V _{CC} - 0.2 | — | V |
| | | | | I _{OH} = -6 mA | 2.3 | 2.0 | — | |
| | | | | I _{OH} = -12 mA | 2.3 | 1.8 | — | |
| | | | | I _{OH} = -18 mA | 2.3 | 1.7 | — | |
| | L-level | V _{OL} | V _{IN} = V _{IH} or V _{IL} | I _{OL} = 100 μA | 2.3 to 2.7 | — | 0.2 | |
| | | | | I _{OL} = 12 mA | 2.3 | — | 0.4 | |
| | | | | I _{OL} = 18 mA | 2.3 | — | 0.6 | |
| | | | | | | | | |
| Input leakage current | | I _{IN} | V _{IN} = 0 to 3.6 V | | 2.3 to 2.7 | — | ±5.0 | μA |
| 3-state output OFF state current | | I _{OZ} | V _{IN} = V _{IH} or V _{IL} V _{OUT} = 0 to 3.6 V | | 2.3 to 2.7 | — | ±10.0 | μA |
| Power-off leakage current | | I _{OFF} | V _{IN} , V _{OUT} = 0 to 3.6 V | | 0 | — | 10.0 | μA |
| Quiescent supply current | | I _{CC} | V _{IN} = V _{CC} or GND | | 2.3 to 2.7 | — | 20.0 | μA |
| | | | V _{CC} ≤ (V _{IN} , V _{OUT}) ≤ 3.6 V | | 2.3 to 2.7 | — | ±20.0 | |

DC Characteristics (Ta = -40 to 85°C, 1.8 V ≤ VCC < 2.3 V)

| Characteristics | | Symbol | Test Condition | | VCC (V) | Min | Max | Unit |
|----------------------------------|---------|------------------|---|---------------------------|------------|-----------------------|-----------------------|------|
| | | | | | | | | |
| Input voltage | H-level | V _{IH} | — | | 1.8 to 2.3 | 0.7 × V _{CC} | — | V |
| | L-level | V _{IL} | — | | 1.8 to 2.3 | — | 0.2 × V _{CC} | |
| Output voltage | H-level | V _{OH} | V _{IN} = V _{IH} or V _{IL} | I _{OH} = -100 μA | 1.8 | V _{CC} - 0.2 | — | V |
| | | | | I _{OH} = -6 mA | 1.8 | 1.4 | — | |
| | L-level | V _{OL} | V _{IN} = V _{IH} or V _{IL} | I _{OL} = 100 μA | 1.8 | — | 0.2 | |
| | | | | I _{OL} = 6 mA | 1.8 | — | 0.3 | |
| Input leakage current | | I _{IN} | V _{IN} = 0 to 3.6 V | | 1.8 | — | ±5.0 | μA |
| 3-state output OFF state current | | I _{OZ} | V _{IN} = V _{IH} or V _{IL} V _{OUT} = 0 to 3.6 V | | 1.8 | — | ±10.0 | μA |
| Power-off leakage current | | I _{OFF} | V _{IN} , V _{OUT} = 0 to 3.6 V | | 0 | — | 10.0 | μA |
| Quiescent supply current | | I _{CC} | V _{IN} = V _{CC} or GND | | 1.8 | — | 20.0 | μA |
| | | | V _{CC} ≤ (V _{IN} , V _{OUT}) ≤ 3.6 V | | 1.8 | — | ±20.0 | |

AC Characteristics (Ta = -40 to 85°C, input: tr = tf = 2.0 ns, CL = 30 pF, RL = 500 Ω)

| Characteristics | Symbol | Test Condition | VCC (V) | Min | Max | Unit |
|-----------------------------------|------------------|------------------------------|-----------|-----|-----|------|
| | | | | | | |
| Maximum clock frequency | fmax | Figure 1, Figure 2 | 1.8 | 100 | — | MHz |
| | | | 2.5 ± 0.2 | 200 | — | |
| | | | 3.3 ± 0.3 | 250 | — | |
| Propagation delay time (CK-Q) | tpLH tpHL | Figure 1, Figure 2 | 1.8 | 1.5 | 8.8 | ns |
| | | | 2.5 ± 0.2 | 0.8 | 4.4 | |
| | | | 3.3 ± 0.3 | 0.6 | 3.5 | |
| Propagation delay time (CLR-Q) | tpHL | Figure 1, Figure 3 | 1.8 | 1.5 | 9.2 | ns |
| | | | 2.5 ± 0.2 | 0.8 | 4.6 | |
| | | | 3.3 ± 0.3 | 0.6 | 3.7 | |
| 3-state output enable time | tpZL tpZH | Figure 1, Figure 4 | 1.8 | 1.5 | 9.8 | ns |
| | | | 2.5 ± 0.2 | 0.8 | 4.9 | |
| | | | 3.3 ± 0.3 | 0.6 | 3.8 | |
| 3-state output disable time | tpLZ tpHZ | Figure 1, Figure 4 | 1.8 | 1.5 | 7.6 | ns |
| | | | 2.5 ± 0.2 | 0.8 | 4.2 | |
| | | | 3.3 ± 0.3 | 0.6 | 3.7 | |
| Minimum pulse width (CK, CLR) | tW (H) tW (L) | Figure 1, Figure 2, Figure 3 | 1.8 | 4.0 | — | ns |
| | | | 2.5 ± 0.2 | 1.5 | — | |
| | | | 3.3 ± 0.3 | 1.5 | — | |
| Minimum set-up time (D, CKEN) | ts | Figure 1, Figure 2, Figure 5 | 1.8 | 2.5 | — | ns |
| | | | 2.5 ± 0.2 | 1.5 | — | |
| | | | 3.3 ± 0.3 | 1.5 | — | |
| Minimum hold time (D, CKEN) | th | Figure 1, Figure 2, Figure 5 | 1.8 | 1.0 | — | ns |
| | | | 2.5 ± 0.2 | 1.0 | — | |
| | | | 3.3 ± 0.3 | 1.0 | — | |
| Minimum removal time | trem | Figure 1, Figure 6 | 1.8 | 4.0 | — | ns |
| | | | 2.5 ± 0.2 | 2.0 | — | |
| | | | 3.3 ± 0.3 | 2.0 | — | |
| Output to output skew | tosLH tosHL | (Note 11) | 1.8 | — | 0.5 | ns |
| | | | 2.5 ± 0.2 | — | 0.5 | |
| | | | 3.3 ± 0.3 | — | 0.5 | |

For CL = 50 pF, add approximately 300 ps to the AC maximum specification.

Note 11: Parameter guaranteed by design.

$$(tosLH = |tpLHm - tpLHn|, tosHL = |tpHLm - tpHLn|)$$

Dynamic Switching Characteristics

($T_a = 25^\circ\text{C}$, input: $t_r = t_f = 2.0 \text{ ns}$, $C_L = 30 \text{ pF}$, $R_L = 500 \Omega$)

| Characteristics | Symbol | Test Condition | V _{CC} (V) | Typ. | Unit |
|--|------------------|--|---------------------|-------|------|
| | | | | | |
| Quiet output maximum dynamic V _{OL} | V _{OLP} | V _{IH} = 1.8 V, V _{IL} = 0 V (Note 12) | 1.8 | 0.25 | V |
| | | V _{IH} = 2.5 V, V _{IL} = 0 V (Note 12) | 2.5 | 0.6 | |
| | | V _{IH} = 3.3 V, V _{IL} = 0 V (Note 12) | 3.3 | 0.8 | |
| Quiet output minimum dynamic V _{OL} | V _{OLV} | V _{IH} = 1.8 V, V _{IL} = 0 V (Note 12) | 1.8 | -0.25 | V |
| | | V _{IH} = 2.5 V, V _{IL} = 0 V (Note 12) | 2.5 | -0.6 | |
| | | V _{IH} = 3.3 V, V _{IL} = 0 V (Note 12) | 3.3 | -0.8 | |
| Quiet output minimum dynamic V _{OH} | V _{OHV} | V _{IH} = 1.8 V, V _{IL} = 0 V (Note 12) | 1.8 | 1.5 | V |
| | | V _{IH} = 2.5 V, V _{IL} = 0 V (Note 12) | 2.5 | 1.9 | |
| | | V _{IH} = 3.3 V, V _{IL} = 0 V (Note 12) | 3.3 | 2.2 | |

Note 12: Parameter guaranteed by design.

Capacitive Characteristics ($T_a = 25^\circ\text{C}$)

| Characteristics | Symbol | Test Condition | V _{CC} (V) | Typ. | Unit |
|-------------------------------|-----------------|------------------------------------|---------------------|------|------|
| | | | | | |
| Input capacitance | C _{IN} | — | 1.8, 2.5, 3.3 | 6 | pF |
| Output capacitance | C _O | — | 1.8, 2.5, 3.3 | 7 | pF |
| Power dissipation capacitance | C _{PD} | f _{IN} = 10 MHz (Note 13) | 1.8, 2.5, 3.3 | 20 | pF |

Note 13: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC(\text{opr})} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/18 \text{ (per bit)}$$

AC Test Circuit

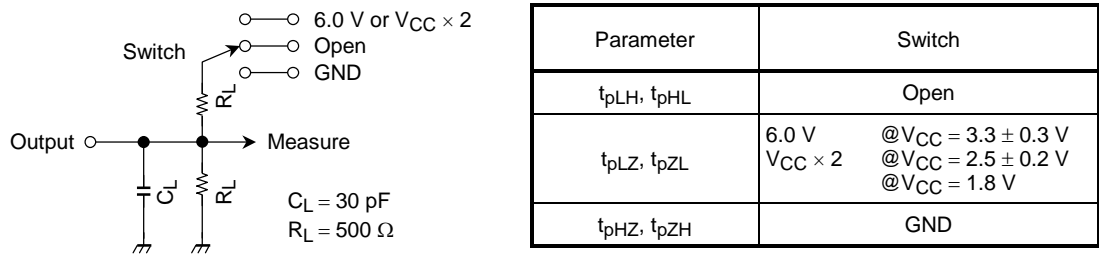


Figure 1

AC Waveform

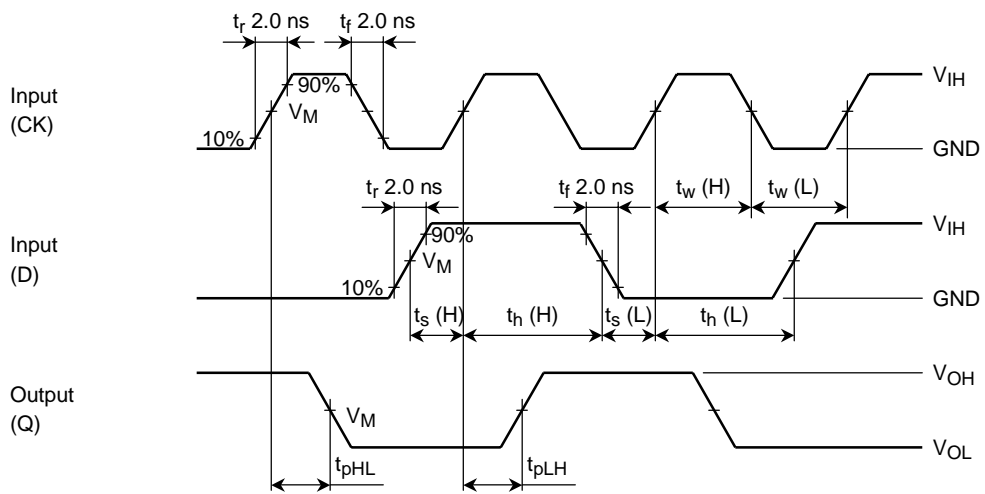


Figure 2 t_{pLH} , t_{pHL} , t_w , t_s , t_h

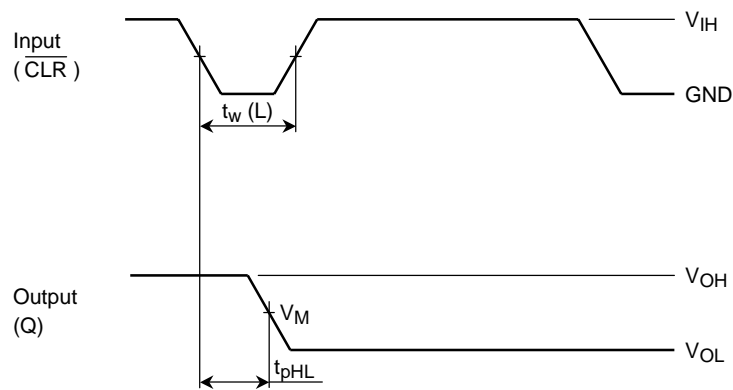


Figure 3 t_{pLH} , t_{pHL}

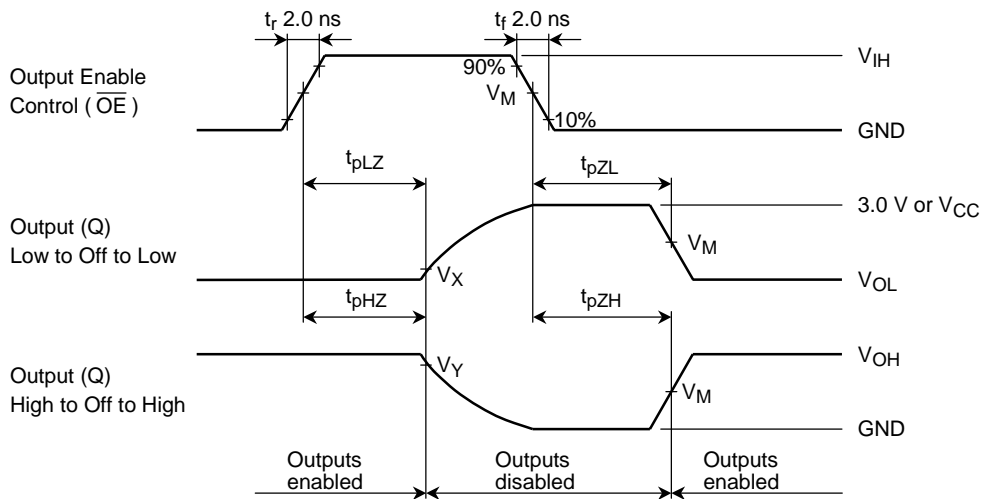


Figure 4 t_{pLZ} , t_{pHZ} , t_{pZL} , t_{pZH}

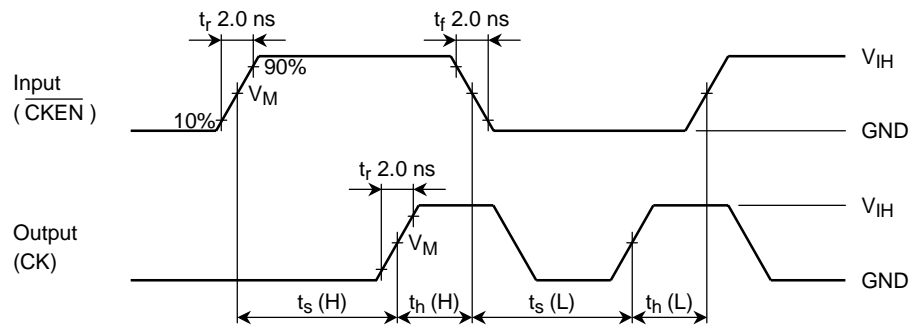


Figure 5 t_s , t_h

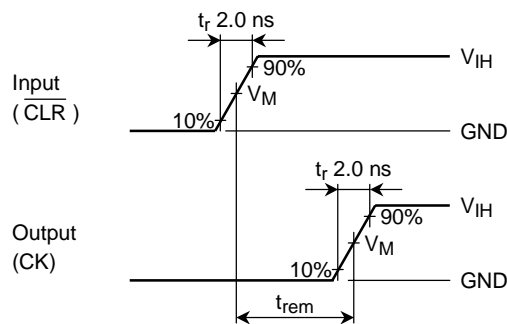


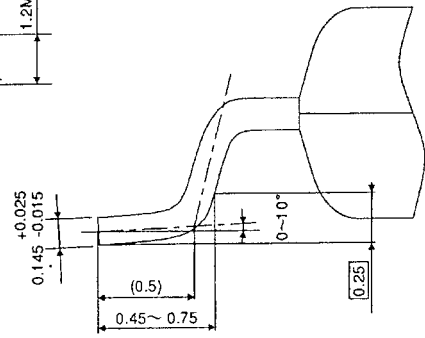
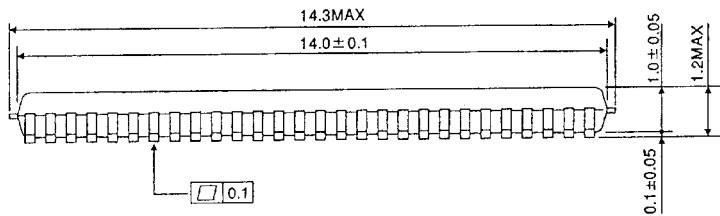
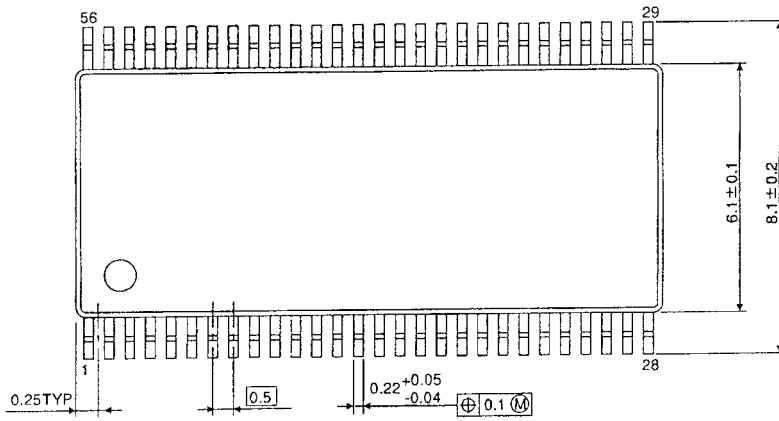
Figure 6 t_{rem}

| Symbol | V_{CC} | | |
|----------|--------------------------|---------------------------|---------------------------|
| | $3.3 \pm 0.3 \text{ V}$ | $2.5 \pm 0.2 \text{ V}$ | 1.8 V |
| V_{IH} | 2.7 V | V_{CC} | V_{CC} |
| V_M | 1.5 V | $V_{CC}/2$ | $V_{CC}/2$ |
| V_X | $V_{OL} + 0.3 \text{ V}$ | $V_{OL} + 0.15 \text{ V}$ | $V_{OL} + 0.15 \text{ V}$ |
| V_Y | $V_{OL} - 0.3 \text{ V}$ | $V_{OL} - 0.15 \text{ V}$ | $V_{OL} - 0.15 \text{ V}$ |

Package Dimensions

TSSOP56-P-0061-0.50

Unit : mm



Weight: 0.25 g (typ.)

RESTRICTIONS ON PRODUCT USE

000707EBA

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The products described in this document are subject to the foreign exchange and foreign trade laws.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.